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With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



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## **IGBT Module**

Sixpack

Short Circuit SOA Capability Square RBSOA

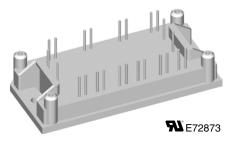
Preliminary data

Part name (Marking on product)

MWI 80-12T6K

10, 23 0 11, 12 15, 16 19, 20 19, 24 0

 $I_{C25} = 80 A$   $V_{CES} = 1200 V$   $V_{CE(sat) typ.} = 2.0 V$ 



Pin configuration see outlines.

#### Features:

- Trench IGBTs
- low saturation voltage
- positive temperature coefficient for easy paralleling
- fast switching
- short tail current for optimized performance also in resonant circuits
- HiPerFRED™ diode:
- fast reverse recovery
- low operating forward voltage
- low leakage current
- Industry Standard Package
- solderable pins for PCB mounting
- isolated copper base plate

#### Application:

- AC drives
- UPS
- Welding

## Package:

- UL registered
- Industry standard E1-pack



				Ratir	ngs	
Symbol	Definitions	Conditions	min.	typ.	max.	Unit
V <sub>CES</sub>	collector emitter voltage	T <sub>vJ</sub> = 25°C to 150°	С		1200	٧
V <sub>GES</sub>	max. DC gate voltage max. transient collector gate voltage	continuous transient			±20 ±30	V
I <sub>C25</sub> I <sub>C80</sub>	collector current	$T_{\rm C} = 25^{\circ}$ $T_{\rm C} = 80^{\circ}$			80 56	A
P <sub>tot</sub>	total power dissipation	$T_{\rm C} = 25^{\circ}$	2		270	W
V <sub>CE(sat)</sub>	collector emitter saturation voltage	$I_{C} = 50 \text{ A}; V_{GE} = 15 \text{ V}$ $T_{VJ} = 25^{\circ} 0$ $T_{VJ} = 125^{\circ} 0$		2.0 2.3	2.4	V V
$V_{\text{GE(th)}}$	gate emitter threshold voltage	$I_{\rm C} = 2 \text{ mA}; V_{\rm GE} = V_{\rm CE}$ $T_{\rm VJ} = 25^{\circ}$	C 4.5		6.5	V
I <sub>CES</sub>	collector emitter leakage current	$V_{CE} = V_{CES}; V_{GE} = 0 \text{ V}$ $T_{VJ} = 25^{\circ}0$ $T_{VJ} = 125^{\circ}0$		0.8	1	mA mA
I <sub>GES</sub>	gate emitter leakage current	$V_{CE} = 0 \text{ V}; \ V_{GE} = \pm 20 \text{ V}$			400	nA
C <sub>ies</sub>	input capacitance	$V_{CE} = 25 \text{ V}; V_{GE} = 0 \text{ V}; f = 1 \text{ MHz}$		3600		pF
$Q_{G(on)}$	total gate charge	$V_{CE} = 600 \text{ V}; V_{GE} = 15 \text{ V}; I_{C} = 50 \text{ A}$		470		nC
$\begin{aligned} & \mathbf{t}_{\mathrm{d(on)}} \\ & \mathbf{t}_{\mathrm{r}} \\ & \mathbf{t}_{\mathrm{d(off)}} \\ & \mathbf{t}_{\mathrm{f}} \\ & \mathbf{E}_{\mathrm{on}} \\ & \mathbf{E}_{\mathrm{off}} \end{aligned}$	turn-on delay time current rise time turn-off delay time current fall time turn-on energy per pulse turn-off energy per pulse	inductive load $V_{CE} = 600 \text{ V; } I_C = 50 \text{ A} $ $V_{GE} = \pm 15 \text{ V; } R_G = 18 \Omega$	0	90 50 520 90 5 6.5		ns ns ns ns mJ mJ
I <sub>CM</sub>	reverse bias safe operating area	RBSOA; $V_{GE} = \pm 15 \text{ V}$ ; $R_G = 18 \Omega$ $L = 100 \mu\text{H}$ ; clamped induct. load $T_{VJ} = 125^{\circ}\text{G}$ $V_{CEmax} = V_{CES} - L_S \cdot \text{di/dt}$	0	100		A
t <sub>sc</sub> (SCSOA)	short circuit safe operating area	$V_{CE} = 900 \text{ V}; V_{GE} = \pm 15 \text{ V};$ $T_{VJ} = 125^{\circ}$ $R_{G} = 18 \Omega;$ non-repetitive	C	10		μs
R <sub>thJC</sub>	thermal resistance junction to case	(per IGBT)			0.46	K/W
R <sub>thCH</sub>	thermal resistance case to heatsink	(per IGBT)		0.2		K/W

Diodes					
Symbol	Definitions	Conditions		Maximum Ra	atings
V <sub>RRM</sub>	max. repetitive reverse voltage			1200	V
I <sub>F25</sub>	forward current		$T_c = 25^{\circ}C$	80	Α
I <sub>F80</sub>			$T_{\rm C} = 80^{\circ}{\rm C}$	51	Α

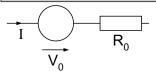
Symbol	Conditions			CI	naracte	ristic Values	
				min.	typ.	max.	
V <sub>F</sub>	forward voltage	I <sub>F</sub> = 50 A	$T_{VJ} = 25^{\circ}C$ $T_{VJ} = 125^{\circ}C$		2.3 1.6	2.6	V
I <sub>RM</sub> t <sub>rr</sub>	max. reverse recovery current reverse recovery time	$V_{R} = 600 \text{ V}; I_{F} = 50 \text{ A}$ $di_{F}/dt = -600 \text{ A}/\mu\text{s}$	T <sub>VJ</sub> = 100°C		35 200		A ns
$R_{\text{thJC}}$	thermal resistance junction to case	(per diode)	$T_{VJ} = 25^{\circ}C$			0.65	K/W
R <sub>thCH</sub>	thermal resistance case to heatsink	(per diode)			0.25		K/W



Tempera	ture Sensor NTC					
				Ratir	ngs	
Symbol	Definitions	Conditions	min.	typ.	max.	Unit
R <sub>25</sub>	resistance	$T_c = 25^{\circ}C$	4.45	4.7	5.0	kΩ
B <sub>25/85</sub>		•		3510		K

Module							
			Ratings				
Symbol	Definitions	Conditions	min.	typ.	max.	Unit	
$T_{VJ}$	operating temperature		-40		125	°C	
$T_{VJM}$	max. virtual junction temperature				150	°C	
T <sub>stg</sub>	storage temperature		-40		125	°C	
V <sub>ISOL</sub>	isolation voltage	$I_{ISOL} \le 1 \text{ mA}; 50/60 \text{ Hz}$			2500	٧~	
M <sub>d</sub>	mounting torque	(M4)	2.0		2.2	Nm	
d <sub>s</sub>	creep distance on surface		12.7			mm	
d <sub>A</sub>	strike distance through air		12.7			mm	
Weight				40		g	

## **Equivalent Circuits for Simulation**



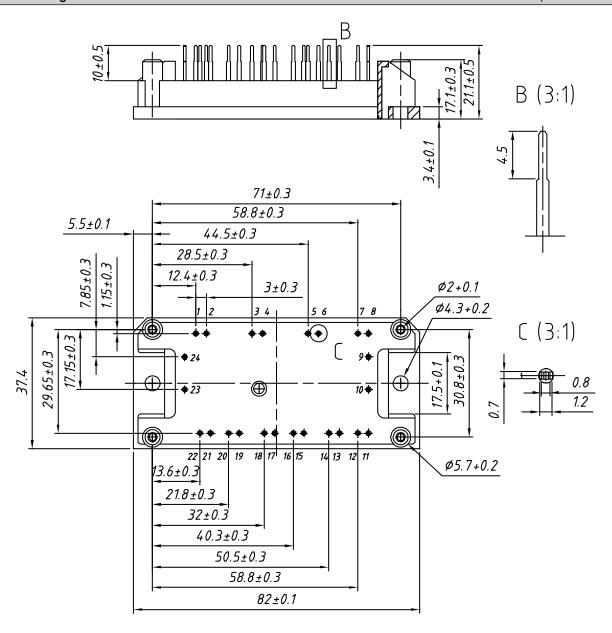
## **Ratings**

Symbol	Definitions	Conditions	min. typ.	max.	Unit
$V_{0}$	IGBT	$T_{vJ} = 125^{\circ}C$	tbd		V
$R_0$			tbd		mΩ
V <sub>o</sub>	free wheeling diode	T <sub>vJ</sub> = 125°C	1.5		V
$R_0$			6		mΩ



**Outline Drawing** 

Dimensions in mm (1 mm = 0.0394")



### **Product Marking**

Ordering	Part Name	Marking on Product	Delivering Mode	Base Qty	Ordering Code
Standard	MWI 80-12T6K	MWI80-12T6K	Box	10	500 159